# NSN 5962-01-311-6450

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View Online at https://aerobasegroup.com/nsn/5962-01-311-6450

# **Overall Height:**

0.330 inches

# **Body Length:**

Between 0.755 inches and 0.785 inches

# **Body Width:**

Between 0.245 inches and 0.280 inches

### **Body Height:**

0.180 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# **Features Provided:**

Hermetically sealed and burn in and high performance and schottky and high speed and 3-state output

#### Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

10 input

### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

7.0 volts power source

# **Time Rating Per Chacteristic:**

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Ram

#### **Memory Capacity:**

Unknown

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

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